NSN 5961-01-113-4165

Thyristor Semiconductor Device - Page 1 of 1



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nclosure Material:
Plastic
Overall Length:
Between 0.575 inches and 0.600 inches
Terminal Length:
0.500 inches
Overall Width:
Between 0.395 inches and 0.410 inches
Function For Which Designed:
Switching
Mounting Facility Quantity:
1
Mounting Method:
Terminal and unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited
Current Rating Per Characteristic:
100.00 amperes forward current, total rms watts
Power Rating Per Characteristic:
16.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius case
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
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Demilitarization:
No
Filg:
A110a0